74LV244

Octal buffer/line driver; 3-state Rev. 03 — 28 September 2007

Product data sheet

1. **General description**

The 74LV244 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC244 and 74HCT244.

The 74LV244 has octal non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs are controlled by the output enable inputs 1OE and 2OE. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. The 74LV244 is identical to the 74LV240 but has non-inverting outputs.

2. Features

- Wide operating voltage: 1.0 V to 5.5 V
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical output ground bounce < 0.8 V at V_{CC} = 3.3 V and T_{amb} = 25 °C
- Typical HIGH-level output voltage (V_{OH}) undershoot: > 2 V at V_{CC} = 3.3 V and $T_{amb} = 25 \, ^{\circ}C$
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

Ordering information 3.

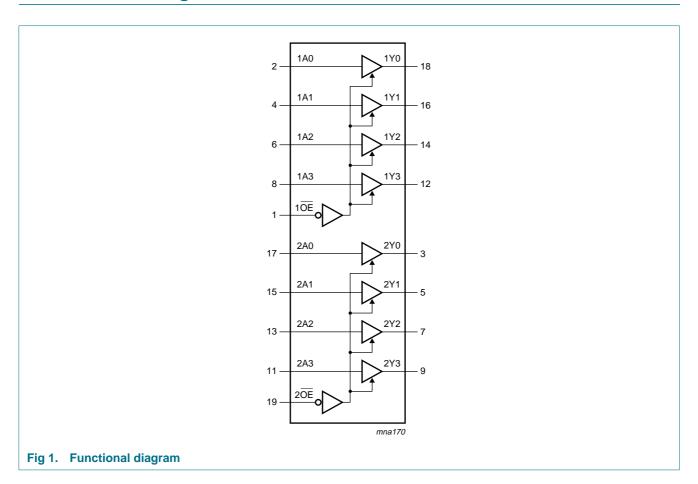
Ordering information Table 1.

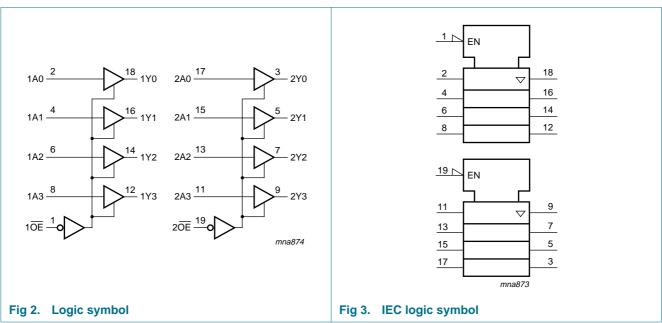
Type number	Package								
	Temperature range	Name	Description	Version					
74LV244N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1					
74LV244D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1					
74LV244DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1					
74LV244PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1					
74LV244BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT764-1					



Octal buffer/line driver; 3-state

4. Functional diagram



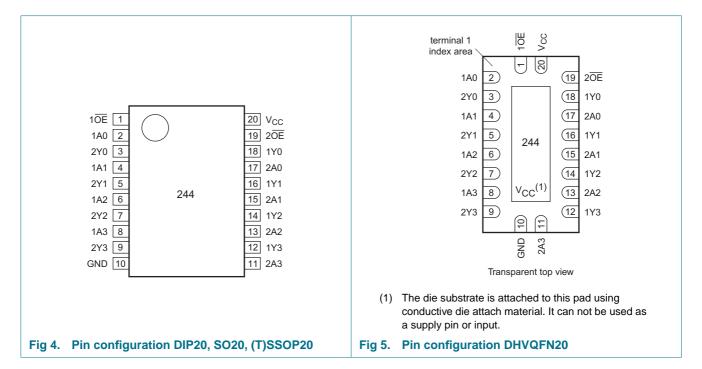


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Octal buffer/line driver; 3-state

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2: Pin description

Symbol	Pin	Description
1 OE	1	output enable input (active LOW)
1A[0:3]	2, 4, 6, 8	data input
2A[0:3]	17, 15, 13, 11	data input
1Y[0:3]	18, 16, 14, 12	data output
2Y[0:3]	3, 5, 7, 9	data output
GND	10	ground (0 V)
2 OE	19	output enable input (active LOW)
V_{CC}	20	supply voltage

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Octal buffer/line driver; 3-state

6. Functional description

Table 3: Function table[1]

Control	Input	Output
nŌĒ	nAn	nYn
L	L	L
L	Н	Н
Н	X	Z

^[1] H = HIGH voltage level;

L = LOW voltage level;

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±50	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I_{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$			
	DIP20 package		[2]	750	mW
	SO20 package		[3] _	500	mW
	(T)SSOP20 package		<u>[4]</u> _	500	mW
	DHVQFN20 package		<u>[5]</u> _	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage[1]		1.0	3.3	5.5	V
V_{I}	input voltage		0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	V

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X = don't care;

Z = high-impedance OFF-state.

^[2] P_{tot} derates linearly with 12 mW/K above 70 °C.

^[3] Ptot derates linearly with 8 mW/K above 70 °C.

^[4] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

^[5] P_{tot} derates linearly with 4.5 mW/K above 60 °C.

Octal buffer/line driver; 3-state

Table 5. Recommended operating conditions ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$	-	-	500	ns/V
		$V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$	-	-	200	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	100	ns/V
		$V_{CC} = 3.6 \text{ V to } 5.5 \text{ V}$	-	-	50	ns/V

^[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to V_{CC} = 5.5 V, but LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).

9. Static characteristics

Table 6. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		$V_{CC} = 2.0 \text{ V}$	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 1.2 \text{ V}$	-	-	0.3	-	0.3	V
		$V_{CC} = 2.0 \text{ V}$	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_O = -100 \mu A; V_{CC} = 1.2 V$	-	1.2	-	-	-	V
		$I_O = -100 \mu A; V_{CC} = 2.0 V$	1.8	2.0	-	1.8	-	V
		$I_O = -100 \mu A; V_{CC} = 2.7 V$	2.5	2.7	-	2.5	-	V
		$I_O = -100 \mu A; V_{CC} = 3.0 V$	2.8	3.0	-	2.8	-	V
		$I_O = -100 \mu A; V_{CC} = 4.5 V$	4.3	4.5	-	4.3	-	V
		$I_O = -8 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.82	-	2.2	-	V
		$I_{O} = -16 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.6	4.2	-	3.5	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_O = 100 \mu A; V_{CC} = 1.2 V$	-	0	-	-	-	V
		$I_O = 100 \mu A; V_{CC} = 2.0 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 2.7 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 3.0 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 4.5 V$	-	0	0.2	-	0.2	V
		$I_O = 8 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.25	0.40	-	0.50	V
		$I_O = 16 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.35	0.55	-	0.65	V
II	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	1.0	μΑ

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Octal buffer/line driver; 3-state

Table 6. Static characteristics ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	–40 °C to +85 °C			-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	5	-	10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20	-	160	μΑ
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μΑ
Cı	input capacitance		-	3.5	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics *GND = 0 V; For test circuit see <u>Figure 8</u>.*

Symbol	Parameter	Conditions		-40	°C to +85	s °C	–40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	nAn to nYn; see Figure 6	[2]						
		$V_{CC} = 1.2 \text{ V}$		-	50	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		-	17	24	-	31	ns
		$V_{CC} = 2.7 \text{ V}$		-	13	17	-	23	ns
		V_{CC} = 3.0 V to 3.6 V; C_L = 15 pF	[3]	-	8	-	-	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	9	14	-	18	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	-	12	-	15	ns
t _{en}	enable time	nOE to nYn; see Figure 7	[2]						
		V _{CC} = 1.2 V		-	65	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		-	22	39	-	49	ns
		$V_{CC} = 2.7 \text{ V}$		-	16	29	-	36	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	12	23	-	29	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	-	19	-	24	ns
t _{dis}	disable time	nOE to nYn; see Figure 7	[2]						
		V _{CC} = 1.2 V		-	60	-	-	-	ns
		V _{CC} = 2.0 V		-	22	34	-	43	ns
		V _{CC} = 2.7 V		-	17	24	-	32	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	13	21	-	26	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	-	16	-	19	ns

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Octal buffer/line driver; 3-state

Dynamic characteristics ...continued Table 7.

GND = 0 V; For test circuit see Figure 8.

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C t	Unit	
				Min	Typ[1]	Max	Min	Max	
C_{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	[4]	-	35	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} . ten is the same as tPZL and tPZH. t_{dis} is the same as t_{PLZ} and t_{PHZ}.
- [3] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$).
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz, f_o = output frequency in MHz

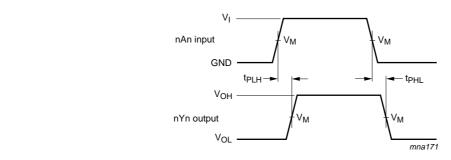
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. The input (nAn) to output (nYn) propagation delays

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Octal buffer/line driver; 3-state

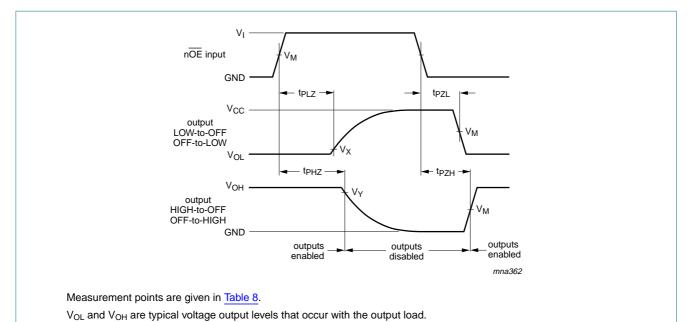
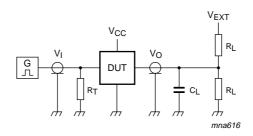


Fig 7. enable and disable times

Table 8: Measurement points

Supply voltage	Input	Output						
V _{CC}	V _M	V _M	V _X	V _Y				
< 2.7 V	0.5V _{CC}	0.5V _{CC}	$V_{OL} + 0.1V_{CC}$	$V_{OH} - 0.1V_{CC}$				
2.7 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V				
≥ 4.5 V	0.5V _{CC}	0.5V _{CC}	V_{OL} + $0.1V_{CC}$	$V_{OH} - 0.1V_{CC}$				

Octal buffer/line driver; 3-state



Test data is given in Table 9.

Definitions test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 8. Load circuit for switching times

Table 9: Test data

Supply voltage	Input		Load		V _{EXT}			
V _{CC}	V _I	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
< 2.7 V	V_{CC}	≤ 2.5 ns	50 pF	1 kΩ	open	GND	2V _{CC}	
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	15 pF, 50 pF	1 kΩ	open	GND	2V _{CC}	
≥ 4.5 V	V _{CC}	≤ 2.5 ns	50 pF	1 kΩ	open	GND	2V _{CC}	

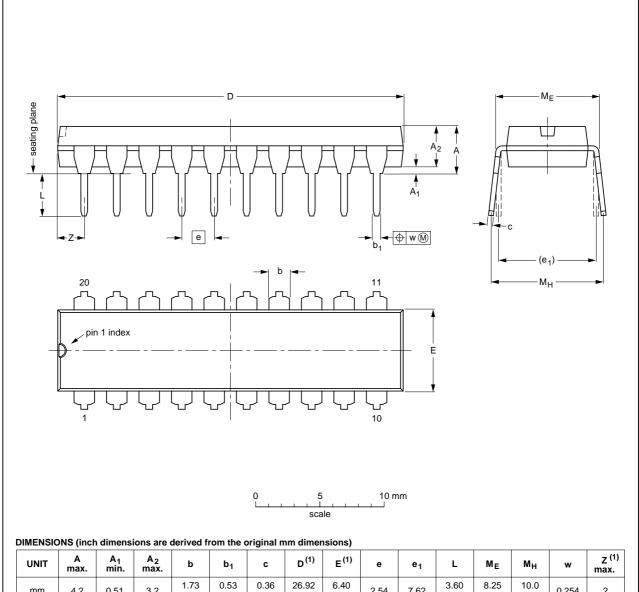
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12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

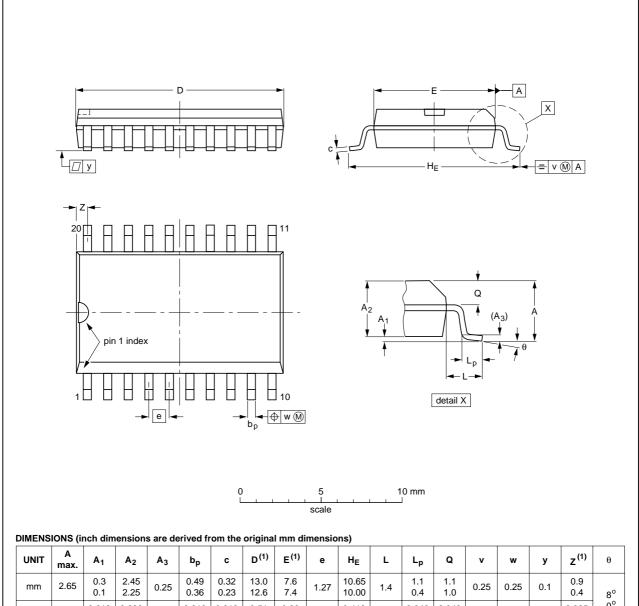
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT146-1		MS-001	SC-603			99-12-27 03-02-13	
					- +	00 02 10	

Fig 9. Package outline SOT146-1 (DIP20)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	V	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

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1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

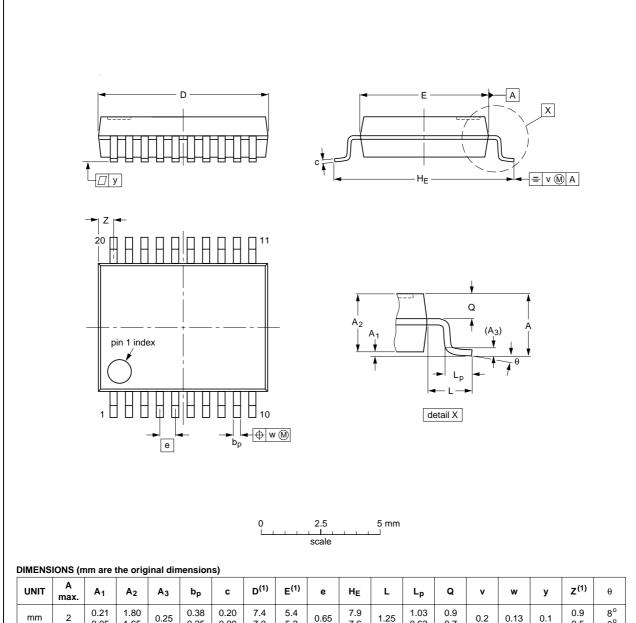
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VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013			99-12-27 03-02-19	

Fig 10. Package outline SOT163-1 (SO20)

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

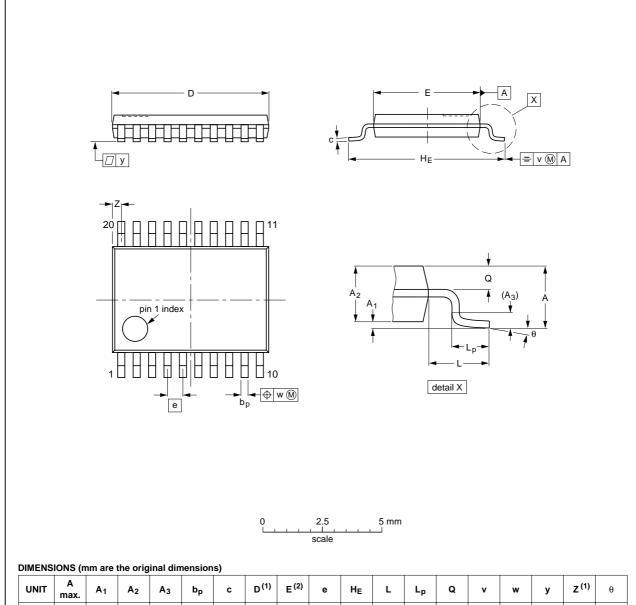
OUTLINE VERSION		REFER	EUROPEAN	ICCUIT DATE		
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT339-1		MO-150				99-12-27 03-02-19

Fig 11. Package outline SOT339-1 (SSOP20)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ	
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°	

Notes

Product data sheet

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT360-1		MO-153				99-12-27 03-02-19
		<u> </u>			·	

Fig 12. Package outline SOT360-1 (TSSOP20)

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74LV244

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

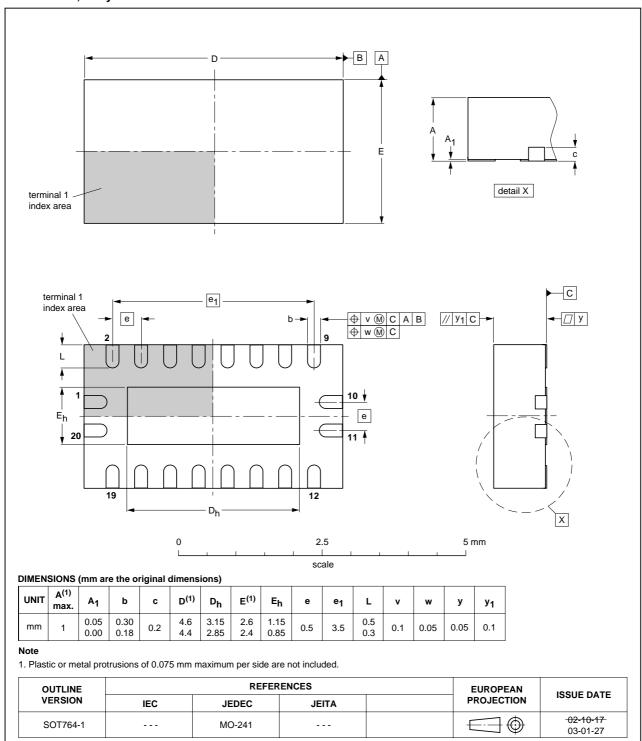


Fig 13. Package outline SOT764-1 (DHVQFN20)

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Octal buffer/line driver; 3-state

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV244_3	20070928	Product data sheet	-	74LV244_2
Modifications:	 The format of this of of NXP Semicondu 	lata sheet has been rede ctors.	signed to comply with the	e new identity guidelines
	 Legal texts have be 	en adapted to the new co	ompany name when appi	opiate.
	 Section 3: DHVQFI 	N20 package added.		
	 Section 8: derating 	values added for DHVQF	FN20 package.	
	Section 12: outline	drawing added for DHVC	FN20 package.	
74LV244_2	19980520	Product specification	-	74LV244_1
74LV244_1	19970219	Product specification	-	-

Octal buffer/line driver; 3-state

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL https://www.nxp.com.

15.2 Definitions

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Octal buffer/line driver; 3-state

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